

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







### 2N2405

# SILICON NPN TRANSISTOR



www.centralsemi.com

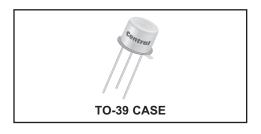
°C

## **DESCRIPTION:**

The CENTRAL SEMICONDUCTOR 2N2405 is a silicon NPN epitaxial planar transistor designed for small signal general purpose switching applications.

**MARKING: FULL PART NUMBER** 

-65 to +200



Operating and Storage Junction Temperature

**MAXIMUM RATINGS:** (T<sub>A</sub>=25°C unless otherwise noted)

SYMBOL UNITS Collector-Base Voltage 120 <sub>V</sub>сво Collector-Emitter Voltage 140 **VCER**  $V_{\mathsf{CEV}}$ V Collector-Emitter Voltage 120 Collector-Emitter Voltage V<sub>CEO</sub> 90 Emitter-Base Voltage 7.0  $V_{EBO}$ Continuous Collector Current 1.0  $I_{C}$ Power Dissipation (T<sub>C</sub>=25°C) W  $P_{\mathsf{D}}$ 5.0 Power Dissipation  $P_{\mathsf{D}}$ 1.0 W

T<sub>J</sub>, T<sub>stg</sub>

FLECTRICAL CHARACTERISTICS: (T<sub>A</sub>=25°C unless otherwise noted)

ELECTRICAL CHARACTERISTICS: (T <sub>A</sub> =25°C unless otherwise noted)  YMBOL TEST CONDITIONS MIN MAX UNITS					
	MIN		UNITS		
V <sub>CB</sub> =90V		10	nA		
V <sub>CB</sub> =90V, T <sub>C</sub> =150°C		10	μΑ		
V <sub>EB</sub> =5.0V		10	nA		
I <sub>C</sub> =100μA	120		V		
$I_C$ =100mA, $R_{BE}$ =10 $\Omega$	140		V		
$I_C$ =100mA, $R_{BE}$ =500 $\Omega$	120		V		
I <sub>C</sub> =100mA	90		V		
I <sub>E</sub> =100μA	7.0		V		
I <sub>C</sub> =50mA, I <sub>B</sub> =5.0mA		0.2	V		
I <sub>C</sub> =150mA, I <sub>B</sub> =15mA		0.5	V		
I <sub>C</sub> =50mA, I <sub>B</sub> =5.0mA		0.9	V		
I <sub>C</sub> =150mA, I <sub>B</sub> =15mA		1.1	V		
$V_{CE}$ =10V, $I_{C}$ =100 $\mu$ A	20				
V <sub>CE</sub> =10V, I <sub>C</sub> =10mA	35				
V <sub>CE</sub> =10V, I <sub>C</sub> =150mA	60	200			
$V_{CE}$ =10V, $I_{C}$ =50mA, f=20MHz	120		MHz		
$V_{CB}$ =10V, $I_E$ =0, f=1.0MHz		15	pF		
$V_{EB}$ =0.5V, $I_{C}$ =0, f=1.0MHz		85	pF		
	TEST CONDITIONS  V <sub>CB</sub> =90V  V <sub>CB</sub> =90V, T <sub>C</sub> =150°C  V <sub>EB</sub> =5.0V  I <sub>C</sub> =100µA  I <sub>C</sub> =100mA, R <sub>BE</sub> =10Ω  I <sub>C</sub> =100mA  I <sub>E</sub> =100µA  I <sub>C</sub> =50mA, I <sub>B</sub> =5.0mA  I <sub>C</sub> =150mA, I <sub>B</sub> =15mA  I <sub>C</sub> =50mA, I <sub>B</sub> =15mA  I <sub>C</sub> =150mA, I <sub>B</sub> =15mA  V <sub>CE</sub> =10V, I <sub>C</sub> =100µA  V <sub>CE</sub> =10V, I <sub>C</sub> =100µA  V <sub>CE</sub> =10V, I <sub>C</sub> =150mA  V <sub>CE</sub> =10V, I <sub>C</sub> =50mA, f=20MHz  V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1.0MHz	TEST CONDITIONS $V_{CB}$ =90V $V_{CB}$ =90V, $T_{C}$ =150°C $V_{EB}$ =5.0V $I_{C}$ =100 $\mu$ A       120 $I_{C}$ =100 $\mu$ A, $I_{E}$ =500 $\Omega$ 120 $I_{C}$ =100 $\mu$ A       90 $I_{E}$ =100 $\mu$ A       7.0 $I_{C}$ =50 $\mu$ A, $I_{B}$ =5.0 $\mu$ A       10 $I_{C}$ =150 $\mu$ A, $I_{B}$ =15 $\mu$ A       10 $I_{C}$ =50 $\mu$ A, $I_{B}$ =15 $\mu$ A       20 $I_{C}$ =10V, $I_{C}$ =100 $\mu$ A       20 $I_{C}$ =10V, $I_{C}$ =100 $\mu$ A       35 $I_{C}$ =10V, $I_{C}$ =150 $\mu$ A       60 $I_{C}$ =10V, $I_{C}$ =50 $\mu$ A, $I_{C}$ =20MHz       120 $I_{C}$ =10V, $I_{C}$ =10V, $I_{C}$ =10MHz       120	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$		

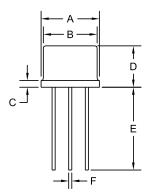
R0 (2-December 2013)

# 2N2405

# SILICON NPN TRANSISTOR

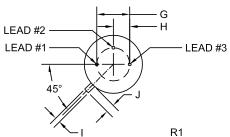


## **TO-39 CASE - MECHANICAL OUTLINE**



DIMENSIONS						
	INCHES		MILLIMETERS			
SYMBOL	MIN	MAX	MIN	MAX		
A (DIA)	0.335	0.370	8.51	9.40		
B (DIA)	0.315	0.335	8.00	8.51		
С	-	0.040	-	1.02		
D	0.240	0.260	6.10	6.60		
Е	0.500	-	12.70	-		
F (DIA)	0.016	0.021	0.41	0.53		
G (DIA)	0.200		5.08			
Н	0.100		2,54			
	0.028	0.034	0.71	0.86		
J	0.029	0.045	0.74	1.14		
TO 30 (DEV): D1)						

TO-39 (REV: R1)



### LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector

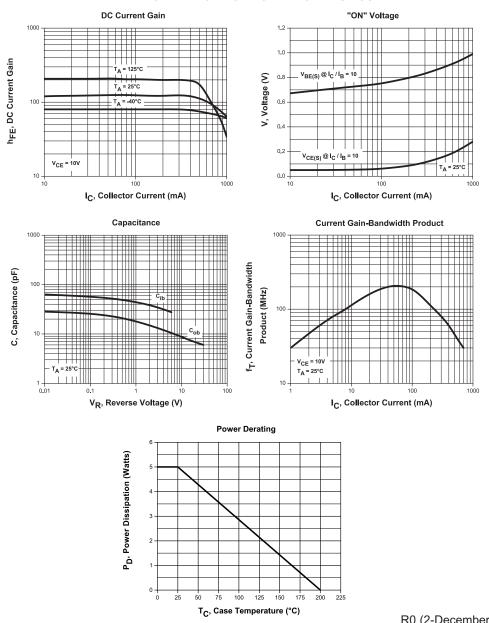
MARKING: FULL PART NUMBER

# 2N2405

# SILICON **NPN TRANSISTOR**



# TYPICAL ELECTRICAL CHARACTERISTICS



## **OUTSTANDING SUPPORT AND SUPERIOR SERVICES**



#### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

#### **DESIGNER SUPPORT/SERVICES**

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2<sup>nd</sup> day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- · Special wafer diffusions
- PbSn plating options
- · Package details
- Application notes
- · Application and design sample kits
- Custom product and package development

#### REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

#### **CONTACT US**

## Corporate Headquarters & Customer Support Team

Central Semiconductor Corp. 145 Adams Avenue Hauppauge, NY 11788 USA

Main Tel: (631) 435-1110 Main Fax: (631) 435-1824

Support Team Fax: (631) 435-3388

www.centralsemi.com

Worldwide Field Representatives: <a href="https://www.centralsemi.com/wwreps">www.centralsemi.com/wwreps</a>

**Worldwide Distributors:** 

www.centralsemi.com/wwdistributors

For the latest version of Central Semiconductor's **LIMITATIONS AND DAMAGES DISCLAIMER**, which is part of Central's Standard Terms and Conditions of sale, visit: <a href="https://www.centralsemi.com/terms">www.centralsemi.com/terms</a>

www.centralsemi.com (001)